## Description

The J100N50X4 is high performance Aluminum Nitride (AIN) half flange termination intended as a cost competitive alternative to Beryllium Oxide ( BeO ). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators, and for use in power combiners. The termination is also RoWS compliant!

## General Specifications

| Resistive Element | Thick Film |
| :--- | :--- |
| Substrate | AIN Ceramic |
| Cover | Alumina Ceramic |
| Mounting Flange | Copper, nickel plated per QC-N-290 |
| Leads | $99 \%$ pure silver (.006" thick) |
| Cover | Alumina Ceramic |

Tolerance is $\pm 0.010$ ", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. All dimensions in inches.

## Electrical Specifications

- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100\% Tested

Half Flange Termination 100 Watts, $50 \Omega$


| Resistance Value: | 50 Ohms, $\pm 2 \%$ |
| :--- | :--- |
| Power: | 100 Watts |
| Frequency Range: | $\mathrm{DC}-3.0 \mathrm{GHz}$ |
| V.S.W.R. | $1.25: 1$ |

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. Storage temperature is $-20^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$. Operating temperature is $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ (see chart for derating temperatures). Specifications subject to change with out notice.

## Outline Drawing



Note: All dimensions in inches -1 inch $=2.54 \mathrm{~cm}$. Lead Length: 0.150 in min.

## Typical Performance:



## Power De-rating:

Mounting Footprint and Procedure:


